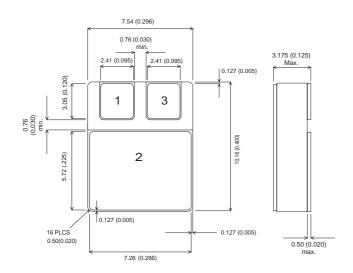




MECHANICAL DATA

Dimensions in mm (inches)



HIGH SPEED MEDIUM VOLTAGE SWITCH

DESCRIPTION

The 2N5154XSMD05 is a silicon expitaxial planar NPN transistors in a Ceramic Surface Mount Package for use in Switching and Linear applications.

SMD05 (TO-276AB)

Underside View

PAD 1 = Base PAD 2 = Collector PAD = 3 - Emitter

ABSOLUTE MAXIMUM RATINGS T_{CASE} = 25°c unless otherwise stated

$\overline{V_{CBO}}$	Collector – Base Voltage (I _E = 0)	100V			
V_{CEO}	Collector – Emitter Voltage (I _B = 0)	80V			
V_{EBO}	Emitter – Base Voltage ($I_C = 0$)	6V			
$I_{\mathbb{C}}$	Continuous Collector Current	5A			
I _{C(PK)}	Peak Collector Current	10A			
I _B	Base Current	1A			
P_{tot}	Total Dissipation at T _{amb} = 25°C	1W			
	T _{case} = 50°C	10W			
	T _{case} = 100°C	6.7W			
T _{stg}	Operating and Storage Temperature Range	−65 to +200°C			
Tj	Junction temperature	200°C			

Semelab Plc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

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2N5154XSMD05

ELECTRICAL CHARACTERISTICS (T_{case} = 25°C unless otherwise stated)

	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
I _{CES}	Collector Cut Off Current	V _{CE} = 60V	V _{BE} = 0			1	μA
		V _{CE} = 100V	$V_{BE} = 0$			1	mA
I _{CEV}	Collector Cut Off Current	V _{CE} = 60V	T _{case} = 150°C			500	μΑ
		$V_{BE} = -2V$					
I _{CEO}	Collector Cut Off Current	$V_{CE} = 40V$	$I_B = 0$			50	
I _{EBO}	Emitter Cut Off Current	$V_{EB} = 4V$	$I_C = 0$			1	μA
		$V_{EB} = 5.5V$	$I_C = 0$			1	mA
V _{CEO(SUS)*}	Collector Emitter Saturation Voltage	I _C = 100mA	I _B = 0	80			V
V _{CE(sat)*}	Collector Emitter Saturation Voltage	I _C = 2.5A	I _B = 250mA			0.75	
		I _C = 5A	$I_B = 500 \text{mA}$			1.5	
V _{BE(sat)*}	Base Emitter Saturation Voltage	I _C = 2.5A	I _B = 250mA			1.45	
		I _C = 5A	I _B = 500mA			2.2	
V_{BE^*}	Base Emitter Voltage	I _C = 2.5A	V _{CE} = 5V			1.45	
h _{FE*}	DC Current Gain	I _C = 50mA	V _{CE} = 5V	50			
		I _C = 2.5A	V _{CE} = 5V	60		200	
			$T_C = -55^{\circ}C$	25			1 —
		I _C = 5A	V _{CE} = 5V	30			
C _{CBO}	Collector Base Capacitance	I _E = 0	V _{CB} = 10V			250	pF
		f = 1MHz					
h _{FE}	Small Signal Current Gain	I _C = 0.1A	V _{CE} = 5V	50			
		f = 1KHz					
		$I_{\rm C} = 0.5A$	V _{CE} = 5v	3.5			_
		f = 20MHz					
t _{on}	Turn On Time	I _C = 5A	V _{CC} = 30v		0.5		
		$I_{B1} = 0.5A$			0.5		
t _{off}	Turn Off Time	I _C = 5A	V _{CC} = 30V		4.0		μs
		$I_{B1} = -I_{B2} = 0.5A$			1.3		

^{*} Pulse test t_p = $300 \mu s$, $\delta < 2\%$

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